DATA SHEET

NEC

BIPOLAR ANALOG INTEGRATED CIRCUIT

μPC3210TB

5 V, SUPER MINIMOLD SILICON MMIC WIDEBAND AMPLIFIER

DESCRIPTION

The μPC3210TB is a silicon monolithic integrated circuits designed as wideband amplifier. The μPC3210TB is suitable to systems required wideband operation from HF to L band.

This IC is manufactured using NEC's 20 GHz f_T NESAT™III silicon bipolar process. This process uses silicon nitride passivation film and gold electrodes. These materials can protect chip surface from external pollution and prevent corrosion/migration. Thus, this IC has excellent performance, uniformity and reliability.

FEATURES

- High-density surface mounting: 6-pin super minimold package (2.0 × 1.25 × 0.9 mm)
- Wideband response : f_u = 2.3 GHz TYP. @3 dB bandwidth
- Supply voltage : V_{CC} = 4.5 to 5.5 V
- Power gain : G_P = 20 dB TYP. @f = 1.5 GHz
- Noise figure : NF = 3.4 dB TYP. @f = 1.5 GHz

APPLICATION

- Systems required wideband operation from HF to 2.0 GHz

ORDERING INFORMATION

Part Number	Package	Marking	Supplying Form
μPC3210TB-E3	6-pin super minimold	C2X	Embossed tape 8 mm wide. 1, 2, 3 pins face the perforation side of the tape. Qty 3 kpcs/reel.

Remark To order evaluation samples, please contact your local NEC sales office. (Part number for sample order: μPC3210TB)

Caution Electro-static sensitive devices

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.
Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

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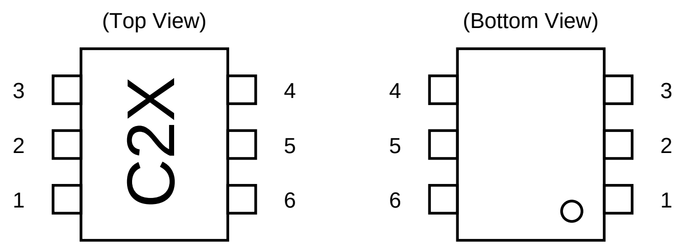
The mark ★ shows major revised points.

PIN CONNECTIONS



Pin No.	Pin Name
1	INPUT
2	GND
3	GND
4	OUTPUT
5	GND
6	V_{CC}

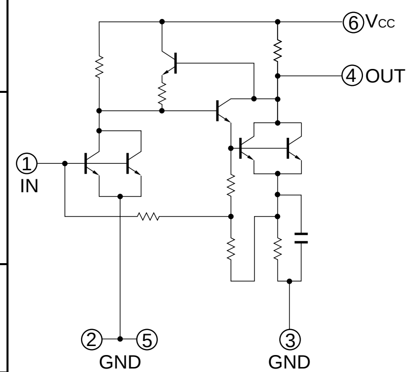
★ PRODUCT LINE-UP OF 5V-BIAS SILICON MMIC WIDEBAND AMPLIFIERS (T_A = +25°C, V_{CC} = 5.0 V, Z_S = Z_L = 50 Ω)

Part No.	f_u (GHz)	$P_{O(sat)}$ (dBm)	G_P (dB)	NF (dB)	I_{CC} (mA)	Package	Marking
μPC2711T	2.9	+1.0	13	5.0 @f = 1.0 GHz	12	6-pin minimold	C1G
μPC2711TB						6-pin super minimold	
μPC2712T	2.6	+3.0	20	4.5 @f = 1.0 GHz	12	6-pin minimold	C1H
μPC2712TB						6-pin super minimold	
μPC2713T	1.2	+7.0	29	3.2 @f = 0.5 GHz	12	6-pin minimold	C1J
μPC2791TB	1.9	+4.0	12	5.5 @f = 0.5 GHz	17	6-pin super minimold	C2S
μPC2792TB	1.2	+5.0	20	3.5 @f = 0.5 GHz	19		C2T
μPC3210TB	2.3	+3.5	20	3.4 @f = 1.5 GHz	15		C2X
μPC3215TB	2.9	+3.5	20.5	2.3 @f = 1.5 GHz	14		C3H

Remark Typical performance. Please refer to ELECTRICAL CHARACTERISTICS in detail.

Caution The package size distinguishes between minimold and super minimold.

PIN EXPLANATION

Pin No.	Pin Name	Applied Voltage (V)	Pin Voltage (V)[Note]	Function and Applications	Internal Equivalent Circuit
1	INPUT	—	0.82	Signal input pin. A internal matching circuit, configured with resistors, enables 50 Ω connection over a wide band. A multi-feedback circuit is designed to cancel the deviations of h_{FE} and resistance. This pin must be coupled to signal source with capacitor for DC cut.	
4	OUTPUT	—	4.0	Signal output pin. A internal matching circuit, configured with resistors, enables 50 Ω connection over a wide band. This pin must be coupled to next stage with capacitor for DC cut.	
6	V_{CC}	4.5 to 5.5	—	Power supply pin. This pin should be externally equipped with bypass capacitor to minimize ground impedance.	
2 3 5	GND	0	—	Ground pin. This pin should be connected to system ground with minimum inductance. Ground pattern on the board should be formed as wide as possible. All the ground pins must be connected together with wide ground pattern to decrease impedance difference.	

Note Pin voltage is measured at V_{CC} = 5.0 V

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Conditions	Ratings	Unit
Supply Voltage	V_{CC}	T_A = +25°C	6.0	V
Circuit Current	I_{CC}	T_A = +25°C	30	mA
★ Power Dissipation	P_D	Mounted on double sided copper clad 50 × 50 × 1.6 mm epoxy glass PWB (T_A = +85°C)	270	mW
Operating Ambient Temperature	T_A		–40 to +85	°C
Storage Temperature	T_{stg}		–55 to +150	°C
Input Power	P_{in}	T_A = +25°C	+10	dBm

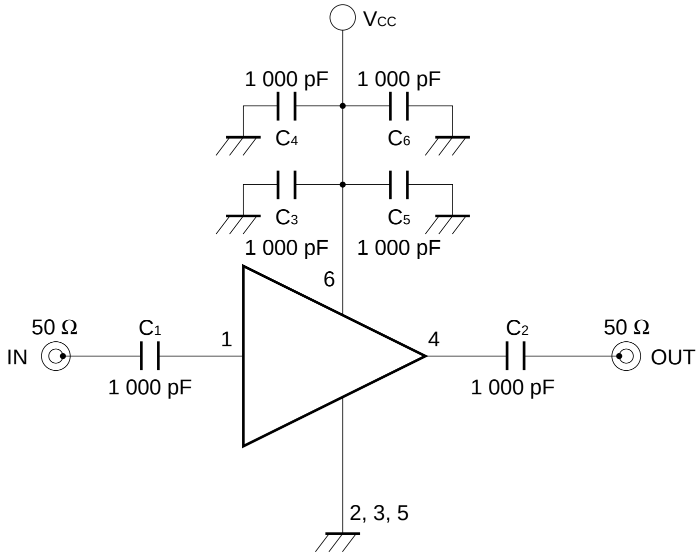
RECOMMENDED OPERATING RANGE

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Supply Voltage	V_{CC}	4.5	5.0	5.5	V
Operating Ambient Temperature	T_A	–40	+25	+85	°C

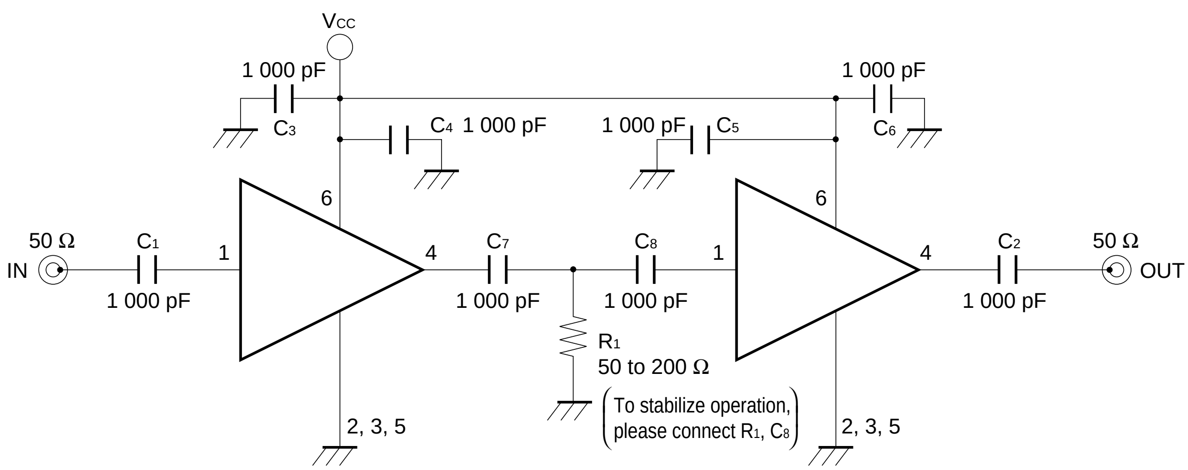
ELECTRICAL OPERATING CONDITIONS (T_A = +25°C, V_{CC} = 5.0 V, Z_S = Z_L = 50 Ω)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Circuit Current	I_{CC}	No signals	11.5	15.0	19.5	mA
Power Gain	G_P	f = 1.5 GHz	18	20	–	dB
Noise Figure	NF	f = 1.5 GHz	–	3.4	4.4	dB
Upper Limit Operating Frequency	f_u	3 dB down below from gain at f = 0.1 GHz	2.05	2.3	–	GHz
Isolation	ISL	f = 1.5 GHz	29	34	–	dB
Input Return Loss	RL_{in}	f = 1.5 GHz	10	14.5	–	dB
Output Return Loss	RL_{out}	f = 1.5 GHz	7	11	–	dB
Saturated Output Level	$P_{O(sat)}$	f = 1.5 GHz, P_{in} = 0 dBm	+0.5	+3.5	–	dBm
Gain Flatness	ΔG_P	f = 0.1 to 2.05 GHz	–	±1.0	–	dB

TEST CIRCUIT



EXAMPLE OF APPLICATION CIRCUIT



The application circuits and their parameters are for reference only and are not intended for use in actual design-ins.

Capacitors for V_{CC}, input and output pins

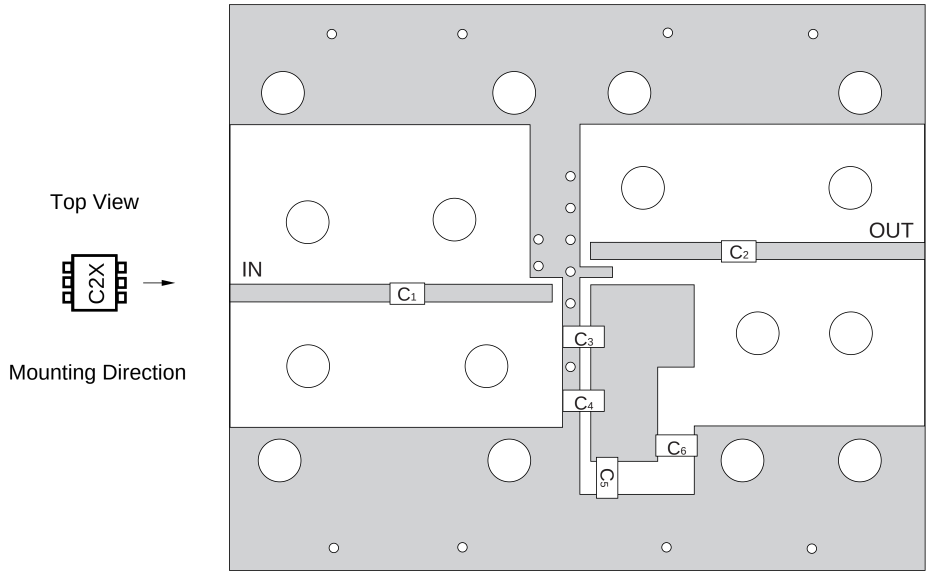
1 000 pF capacitors are recommendable as bypass capacitor for V_{CC} pin and coupling capacitors for input/output pins.

Bypass capacitor for V_{CC} pin is intended to minimize V_{CC} pin's ground impedance. Therefore, stable bias can be supplied against V_{CC} fluctuation.

Coupling capacitors for input/output pins are intended to minimize RF serial impedance and cut DC.

To get flat gain from 100 MHz up, 1 000 pF capacitors are assembled on the test circuit. [Actually, 1 000 pF capacitors give flat gain at least 10 MHz. In the case of under 10 MHz operation, increase the value of coupling capacitor such as 2 200 pF. Because the coupling capacitors are determined by the equation of $C = 1/(2 \pi fZs)$.]

ILLUSTRATION OF THE TEST CIRCUIT ASSEMBLED ON EVALUATION BOARD



COMPONENT LIST

	Value
C_1 to C_6	1 000 pF

Notes

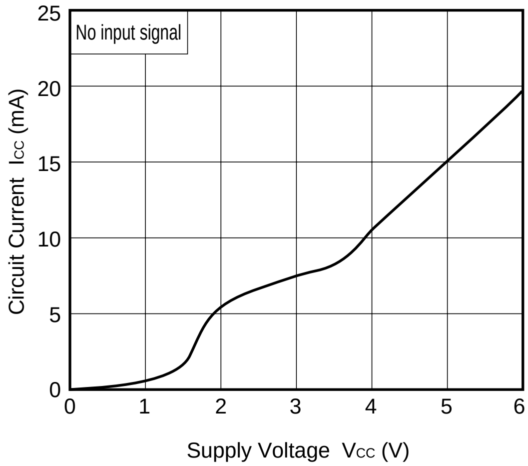
1. 42 × 35 × 0.4 mm double sided copper clad polyimide board.
2. Solder plated on pattern
3. Back side: GND pattern
4. o ○: Through holes

For more information on the use of this IC, refer to the following application note:

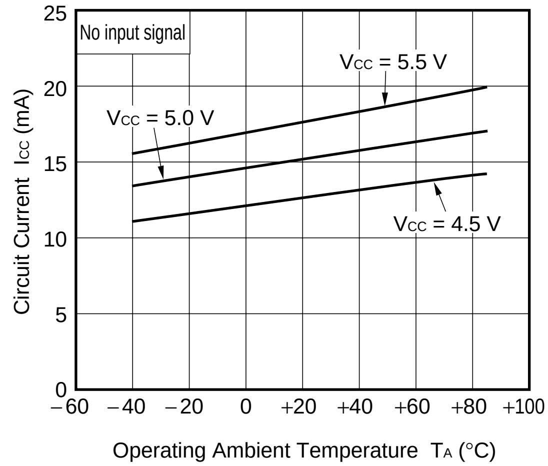
USAGE AND APPLICATIONS OF 6-PIN MINI-MOLD, 6-PIN SUPER MINI-MOLD SILICON HIGH-FREQUENCY WIDEBAND AMPLIFIER MMIC (P11976E).

TYPICAL CHARACTERISTICS (Unless otherwise specified, T_A = +25°C)

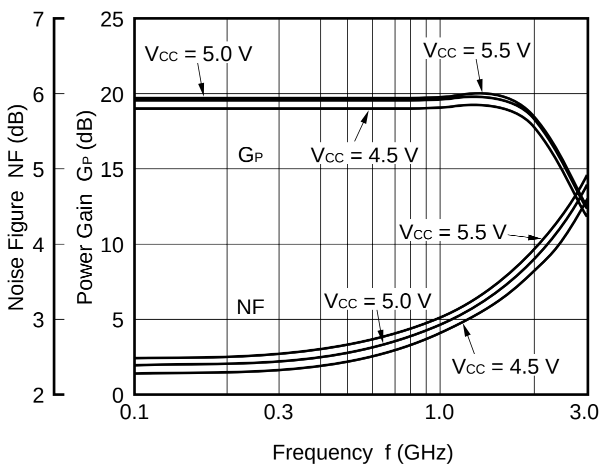
CIRCUIT CURRENT vs. SUPPLY VOLTAGE



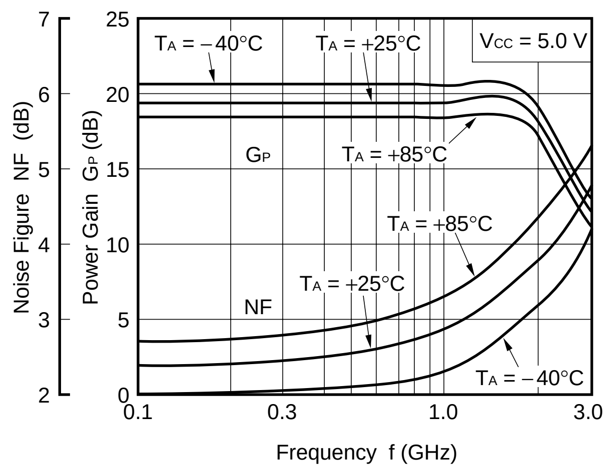
CIRCUIT CURRENT vs.
OPERATING AMBIENT TEMPERATURE



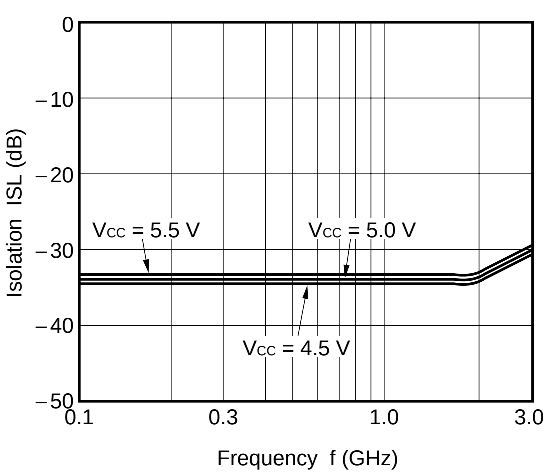
NOISE FIGURE, POWER GAIN
vs. FREQUENCY



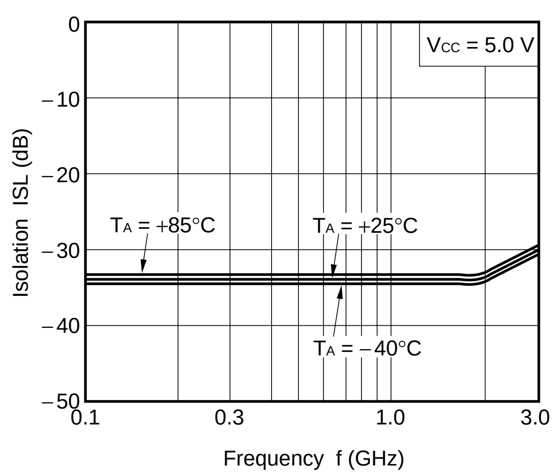
NOISE FIGURE, POWER GAIN
vs. FREQUENCY



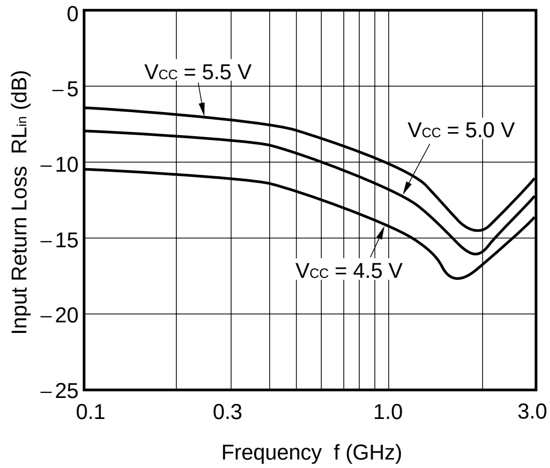
ISOLATION vs. FREQUENCY



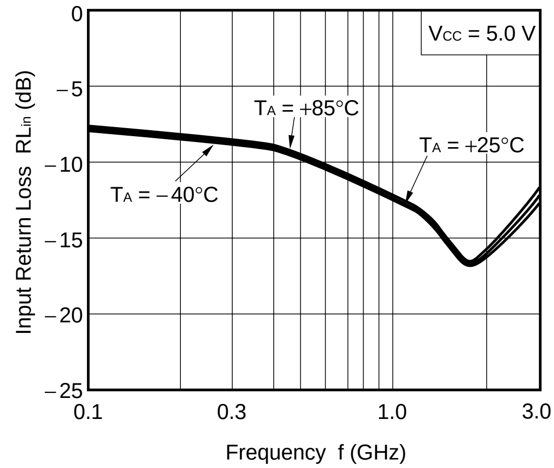
ISOLATION vs. FREQUENCY



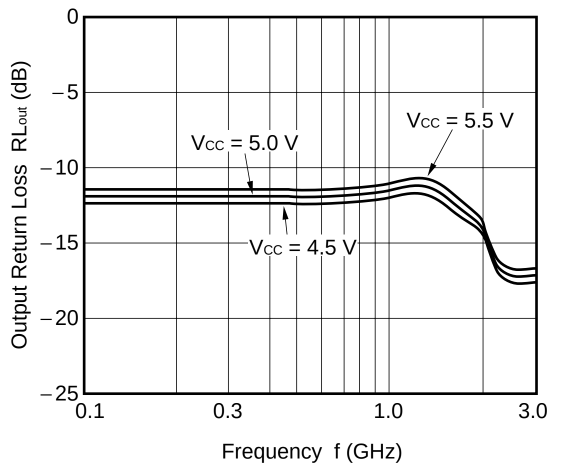
INPUT RETURN LOSS vs. FREQUENCY



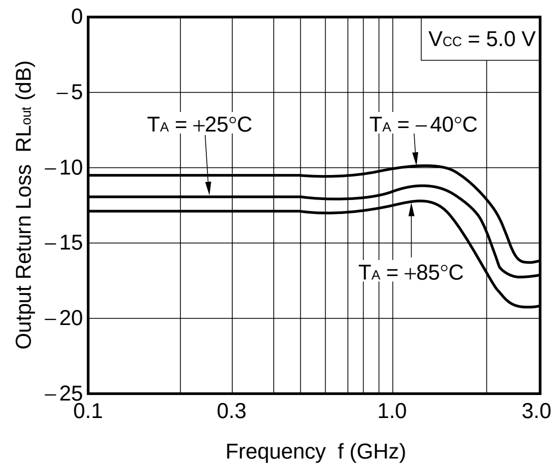
INPUT RETURN LOSS vs. FREQUENCY



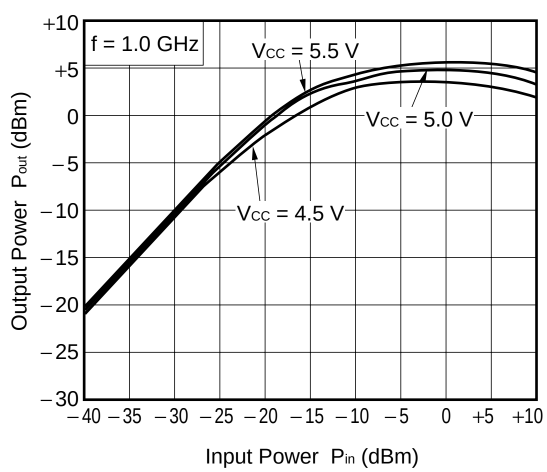
OUTPUT RETURN LOSS vs. FREQUENCY



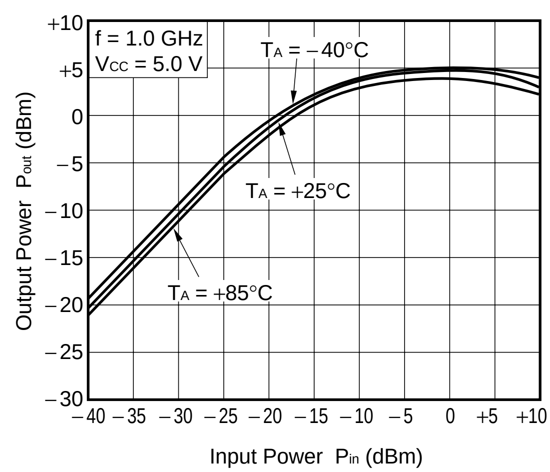
OUTPUT RETURN LOSS vs. FREQUENCY



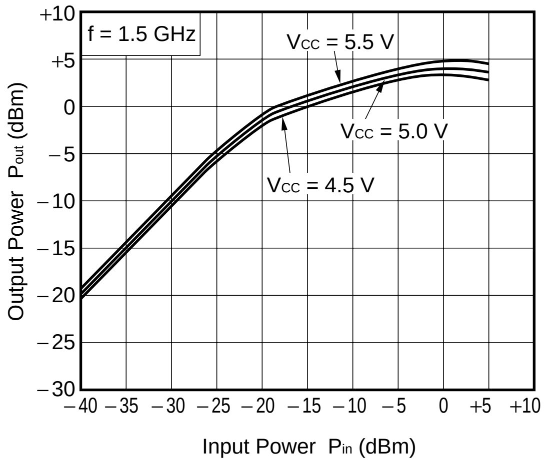
OUTPUT POWER vs. INPUT POWER



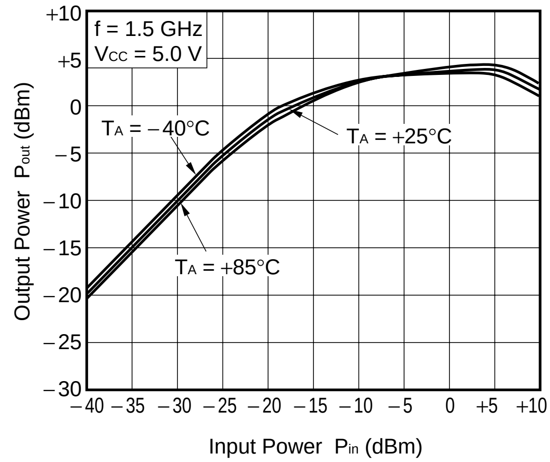
OUTPUT POWER vs. INPUT POWER



OUTPUT POWER vs. INPUT POWER



OUTPUT POWER vs. INPUT POWER



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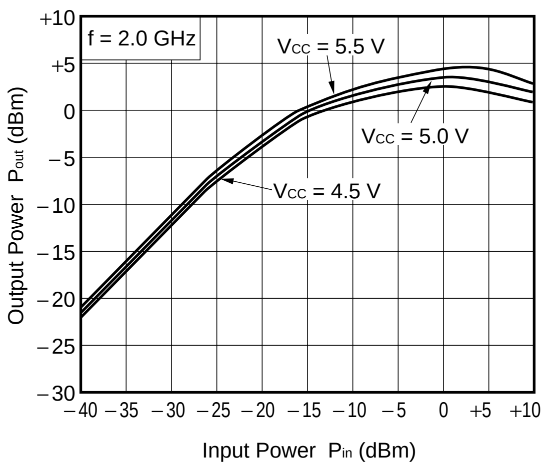
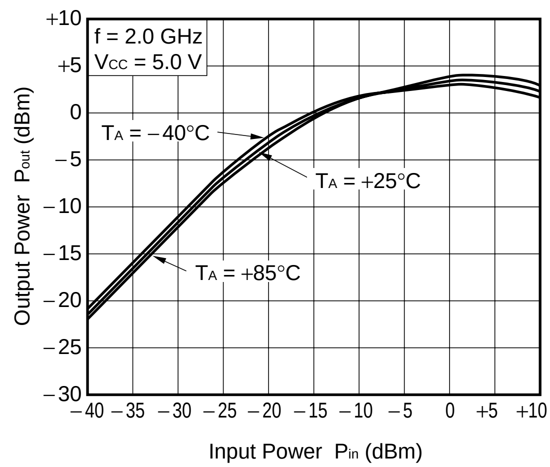
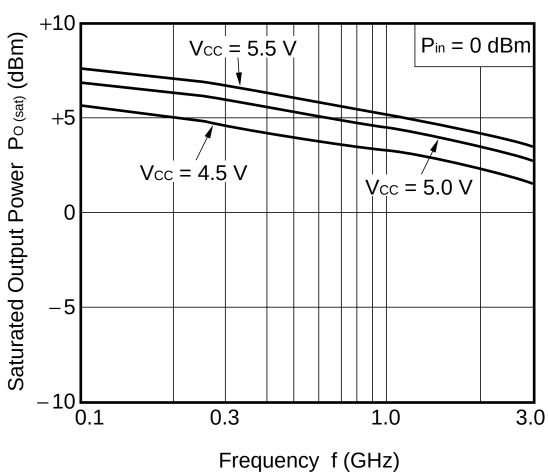


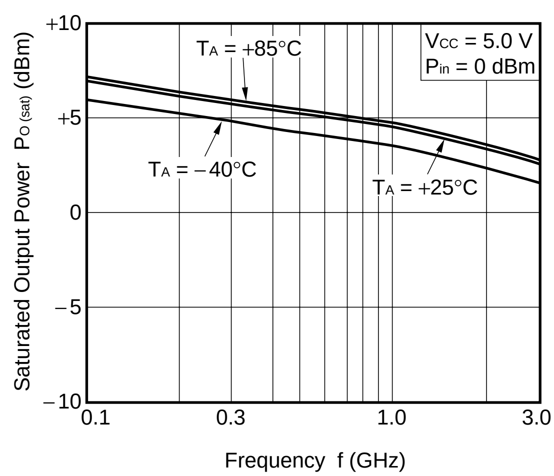
OUTPUT POWER vs. INPUT POWER

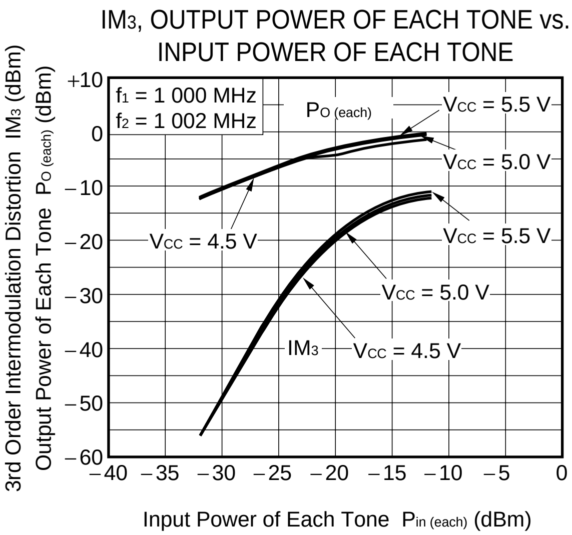


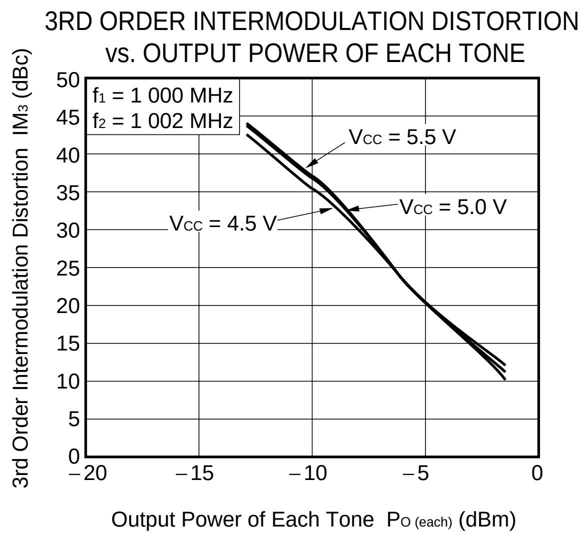
SATURATED OUTPUT POWER
vs. FREQUENCY

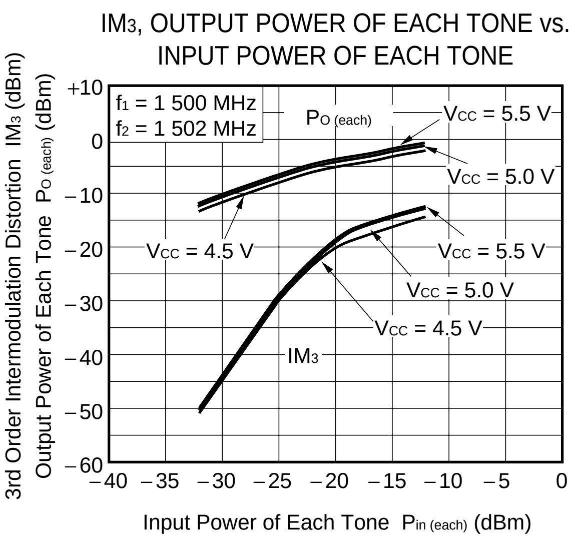


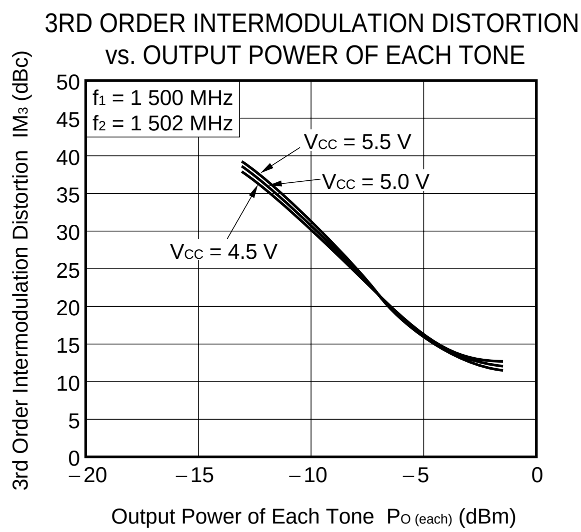
SATURATED OUTPUT POWER
vs. FREQUENCY

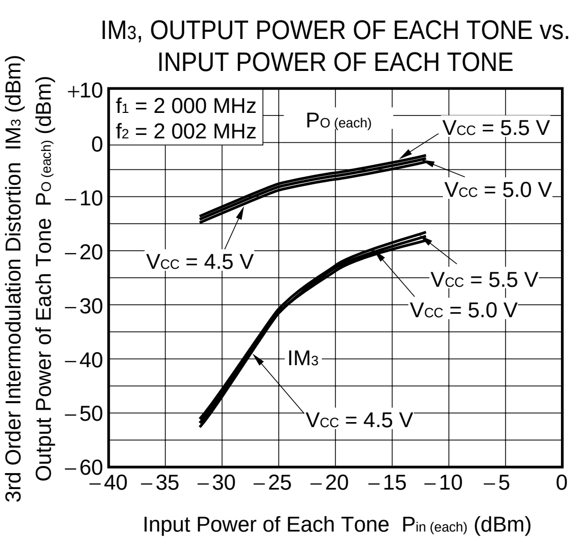


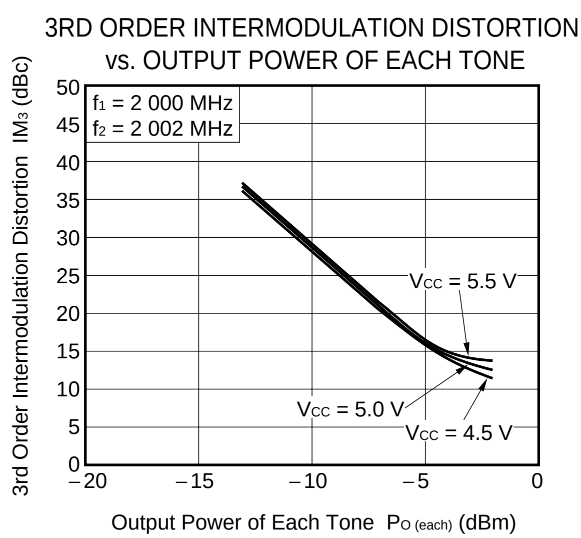








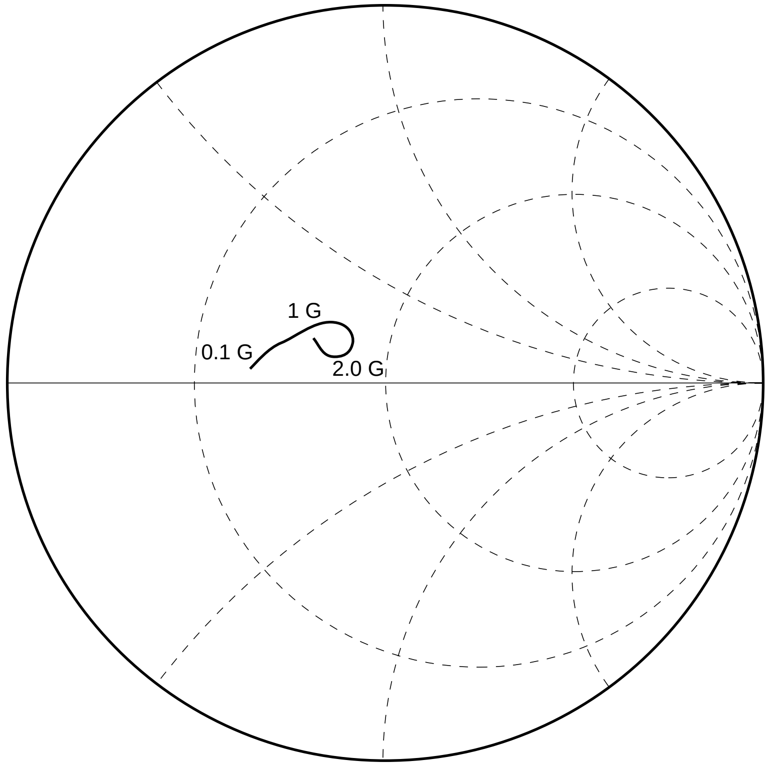




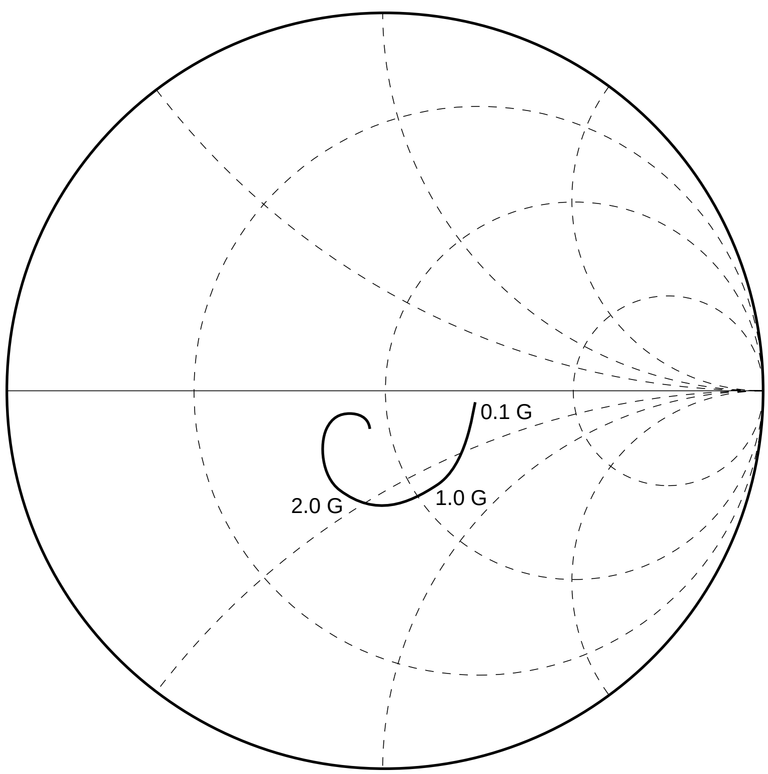
Remark The graphs indicate nominal characteristics.

S-PARAMETERS (T_A = +25°C, V_{CC} = 5.0 V)

S_{11}–FREQUENCY



S_{22}–FREQUENCY



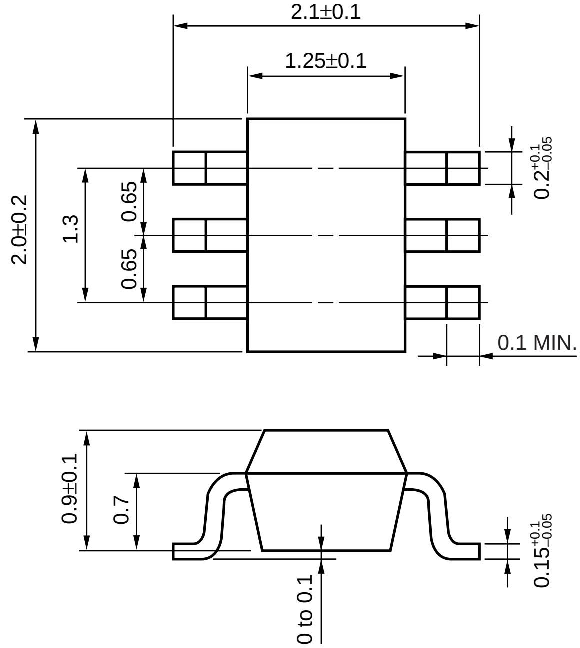
TYPICAL S-PARAMETER VALUES (T_A = +25°C)

V_{CC} = 5.0 V, I_{CC} = 16 mA

FREQUENCY	S_{11}		S_{21}		S_{12}		S_{22}		K
MHz	MAG.	ANG.	MAG.	ANG.	MAG.	ANG.	MAG.	ANG.	
100.0000	0.358	171.9	8.688	–4.4	0.019	–1.4	0.233	–6.8	2.63
200.0000	0.335	166.6	8.807	–10.6	0.019	3.3	0.237	–12.0	2.71
300.0000	0.321	160.7	8.821	–17.1	0.019	6.3	0.233	–15.1	2.68
400.0000	0.306	158.3	8.841	–23.3	0.019	9.9	0.233	–20.6	2.68
500.0000	0.294	154.4	8.908	–29.2	0.019	13.6	0.241	–25.6	2.67
600.0000	0.283	151.8	8.990	–35.1	0.019	15.8	0.246	–30.8	2.74
700.0000	0.273	148.6	9.160	–41.0	0.019	19.5	0.250	–35.8	2.67
800.0000	0.267	146.0	9.342	–47.3	0.018	24.3	0.256	–41.2	2.65
900.0000	0.260	144.2	9.541	–53.9	0.018	29.8	0.263	–47.9	2.69
1000.0000	0.252	141.5	9.741	–60.8	0.019	28.9	0.274	–53.1	2.46
1100.0000	0.246	138.4	10.071	–68.6	0.019	29.4	0.283	–59.0	2.37
1200.0000	0.239	135.9	10.393	–76.3	0.018	36.7	0.291	–65.7	2.38
1300.0000	0.229	133.3	10.513	–85.4	0.019	38.1	0.299	–71.9	2.25
1400.0000	0.224	131.1	10.763	–94.5	0.019	45.6	0.303	–79.7	2.20
1500.0000	0.215	127.4	10.708	–104.0	0.021	48.2	0.311	–87.6	2.05
1600.0000	0.203	125.8	10.720	–114.2	0.021	48.9	0.316	–94.9	2.07
1700.0000	0.191	123.1	10.388	–124.1	0.023	55.7	0.308	–103.4	1.98
1800.0000	0.179	122.1	9.993	–133.7	0.023	59.5	0.303	–111.5	2.02
1900.0000	0.163	121.0	9.507	–142.8	0.025	61.9	0.291	–119.5	2.01
2000.0000	0.155	123.4	8.983	–151.2	0.024	65.9	0.275	–128.4	2.17
2100.0000	0.140	126.1	8.384	–158.9	0.027	69.0	0.255	–135.0	2.14
2200.0000	0.133	129.1	7.905	–166.0	0.029	70.7	0.230	–140.5	2.12
2300.0000	0.130	135.3	7.412	–172.3	0.032	71.8	0.207	–145.9	2.10
2400.0000	0.133	139.0	6.976	–178.6	0.034	74.3	0.182	–150.3	2.12
2500.0000	0.137	144.0	6.582	176.1	0.038	73.2	0.157	–151.8	2.06
2600.0000	0.149	148.5	6.202	170.4	0.039	71.4	0.136	–152.1	2.13
2700.0000	0.157	150.2	5.942	164.9	0.043	73.7	0.116	–147.1	2.03
2800.0000	0.170	152.2	5.567	159.7	0.045	72.2	0.102	–137.8	2.04
2900.0000	0.181	150.3	5.360	153.9	0.047	72.5	0.099	–132.3	2.03
3000.0000	0.203	149.0	5.013	149.0	0.048	69.6	0.104	–122.3	2.10
3100.0000	0.209	147.9	4.810	142.9	0.051	71.0	0.117	–114.4	2.08

★ **PACKAGE DIMENSIONS**

6-PIN SUPER MINIMOLD (UNIT: mm)



NOTES ON CORRECT USE

(1) Observe precautions for handling because of electro-static sensitive devices.

(2) Form a ground pattern as widely as possible to minimize ground impedance (to prevent undesired oscillation). All the ground pins must be connected together with wide ground pattern to decrease impedance difference.

(3) The bypass capacitor should be attached to V_{CC} line.

(4) The DC cut capacitor must be each attached to input and output pin.

RECOMMENDED SOLDERING CONDITIONS

This product should be soldered in the following recommended conditions. Other soldering methods and conditions than the recommended conditions are to be consulted with our sales representatives.

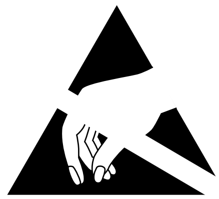
Soldering Method	Soldering Conditions	Recommended Condition Symbol
Infrared Reflow	Package peak temperature: 235°C or below Time: 30 seconds or less (at 210°C) Count: 3, Exposure limit[Note]: None	IR35-00-3
VPS	Package peak temperature: 215°C or below Time: 40 seconds or less (at 200°C) Count: 3, Exposure limit[Note]: None	VP15-00-3
Wave Soldering	Soldering bath temperature: 260°C or below Time: 10 seconds or less Count: 1, Exposure limit[Note]: None	WS60-00-1
Partial Heating	Pin temperature: 300°C Time: 3 seconds or less (per side of device) Exposure limit[Note]: None	–

Note After opening the dry pack, keep it in a place below 25°C and 65% RH for the allowable storage period.

Caution Do not use different soldering methods together (except for partial heating).

For details of recommended soldering conditions for surface mounting, refer to information document SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL (C10535E).

[MEMO]



ATTENTION
OBSERVE PRECAUTIONS
FOR HANDLING
ELECTROSTATIC
SENSITIVE
DEVICES

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